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**Large Seebeck Effect in CrSb<sub>2</sub> Single Crystals** BRIAN SALES, ANDREW MAY, MICHAEL MCGUIRE, DAVID SINGH, Oak Ridge National Laboratory, DAVID MANDRUS, University of Tennessee — CrSb<sub>2</sub> is a narrow gap semiconductor ( $E_g = 0.14$  meV) that orders antiferromagnetically at  $T_N = 273$  K. Resistivity, Hall effect, Seebeck coefficient, thermal conductivity, heat capacity, and magnetic susceptibility data are reported for CrSb<sub>2</sub> single crystals. In spite of some unusual features in electrical transport and Hall measurements below 100 K, only one phase transition occurs ( $T_N$ ) in the temperature range from 2 to 750 K. Many of the low temperature properties can be explained by the thermal depopulation of carriers from the conduction band into a low mobility impurity band about 16 meV below the conduction band edge. The Seebeck coefficient,  $S$ , is large and negative from 2 to 300 K, ranging from  $-70 \mu\text{V}/\text{K}$  at 300 K to  $-4500 \mu\text{V}/\text{K}$  at 18 K. The large magnitude of  $S$  at 18 K is likely due to phonon drag, with the large decrease in the magnitude of  $S$  below 18 K due to the thermal depopulation of the high mobility conduction band. The CrSb<sub>2</sub> Seebeck data are compared to some of the data reported for FeSb<sub>2</sub> and FeSi. This research was supported by the U. S. Department of Energy, Basic Energy Sciences, Materials Sciences and Engineering Division.

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